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Helical transport in helical crystals

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Inversion asymmetric systems i.e. Te (tellurium)

- Weyl semimetals
- Chiral transport in crystals with helical lattice structure

Hirayama, Okugawa, Ishibashi, SM, Miyake, PRL 114, 206401 (2015)

Collaborators:

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- AIST, Tsukuba, Japan
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NI-TI phase transitions and Weyl semimetals



TI: topological insulator

NI: normal insulator

SM, New J. Phys. ('07). SM. Kuga, PRB ('08) SM, Physica E43, 748 ('11)

Z_2 topological number **v**

v=0: normal insulator (NI) v=1: topological insulator (TI)



Formulae are different between (A) & (B)

 \rightarrow How does the TI-NI phase transition occur in (A) & (B)?



Universal phase diagram in 3D

SM, New J. Phys. ('07). SM. Kuga, PRB ('08) SM, Physica E43, 748 ('11)



(δ : inversion symmetry breaking)

(m : external parameter)

Systems with inversion symmetry



Systems without inversion symmetry



<u>3D</u> Weyl nodes = monopole or antimonopole for Berry curvature



- Weyl nodes are either monopole or antimonopole
- Quantized monopole charge
 - C. Herring, Phys. Rev. 52, 365 (1937).
 - G. E. Volovik, The Universe in a Helium Droplet (2007).
 - S. Murakami, New J. Phys. 9, 356 (2007).

Weyl semimetal

 \rightarrow Bulk 3D Dirac cones without degeneracy

Either time-reversal or inversion symmetry must be broken



SM, NJP ('07).

• Surface Fermi arc – connecting between Weyl nodes



Phys. Rev. B (2014)

Search for Weyl semimetals without inversion symmetry

Start from an insulator

 \rightarrow suppose a gap closes by changing a parameter m



Classification by space groups & *k*-points.

230 space groups





	<mark>1</mark> 2	3	4	5	6	7	8	9	10	11	12	13	14	15	10	1/	18	19	20
2	1 22	23	24	25	26	27	28	29	30	31	32	33	34	35	36	37	38	39	40
4	1 42	43	44	45	46	47	48	49	50	51	52	53	54	55	56	57	58	59	60
6	1 62	63	64	65	66	67	68	69	70	71	72	73	74	75	76	77	78	79	<mark>80</mark>
8	1 82	83	84	85	86	87	88	89	90	91	92	93	94	95	96	97	98	99	100
10	1 102	103	104	105	106	107	108	109	110	111	112	113	114	115	116	117	118	119	120
12	1 122	123	124	125	126	127	128	129	130	131	132	133	134	135	136	137	138	139	140
14	1 142	143	144	145	146	147	148	149	150	151	152	153	154	155	156	157	158	159	<u>160</u>
16	<mark>1</mark> 162	163	164	165	166	167	168	169	170	171	172	173	174	175	176	177	178	179	<mark>180</mark>
18	1 182	183	184	185	186	187	188	189	190	191	192	193	194	195	196	197	198	<u>199</u>	200
20	1 202	203	204	205	206	207	208	209	210	211	212	213	214	215	216	217	218	219	220
22	1 222	223	224	225	226	227	228	229	230										

No inversion sym.

 $156 P3m1 C_{3v}^1$

(F1; K6; K7; M5; Z1.)

 $\begin{array}{lll} \Gamma & {\rm G}_{12}^4: \{C_3^+\mid 000\}, \{\sigma_{v_1}\mid 000\}; \ 3, 3; \ 4, 3; \ 6, 2: \ a. \\ M & {\rm G}_{12}^4\otimes {\rm T}_2; \ \{\sigma_{v_1}\mid 000\}, \{\tau_{v_2}\mid 2, 3; \ 4, 3: \ b. \\ A & {\rm G}_{12}^4\otimes {\rm T}_2; \ \{C_3^+\mid 000\}, \{\sigma_{v_1}\mid 000\}; \ t_3; \ 3, 3; \ 4, 3; \ 6, 2: \ a. \\ L & {\rm G}_{4}^4\otimes {\rm T}_2; \ \{\sigma_{v_1}\mid 000\}, \{\tau_{v_2}\mid 000\}; \ t_3; \ 2, 3; \ 4, 3; \ b. \\ K & {\rm G}_{10}^6\otimes {\rm T}_3; \ \{C_3^+\mid 000\}; \ t_1 \ {\rm or} \ t_2; \ 2, 2; \ 4, 2; \ 6, 2: \ a. \\ H & {\rm G}_{10}^6\otimes {\rm T}_3 \otimes {\rm T}_2; \ \{C_3^+\mid 000\}; \ t_1 \ {\rm or} \ t_2; \ t_3; \ 2, 2; \ 4, 2; \ 6, 2: \ a. \\ \end{array}$

- high-symmetry points (TRIM)

high-symmetry points (non TRIM)

high-symmetry lines

"The Mathematical Theory of Symmetry in Solids", Bradley, Cracknell Each k point \rightarrow k group

(Example): C_2 symmetry (i.e. k = invariant under C_2)

 C_2 eigenvalue = +1 or -1

(i) Same signs of C_2 gap cannot close at k – level repulsion

Κ

 (ii) <u>Different signs of C₂</u> gap closing

 → Weyl semimetal monopole-antimonopole pair creation

 \rightarrow move along a symmetry line





Systems without inversion symmetry

 \rightarrow Classification of parametric gap-closing

(a) Metal (gap closes along a loop) – mirror symmetric

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Only two possibilities. No insulator-to-insulator transition happens.

Topological Effects in Tellurium and Selenium

Hirayama, Okugawa, Ishibashi, Murakami, Miyake, PRL 114, 206401 (2015)



Group-VI elements : Te and Se

Trigonal: $P3_121$ or $P3_221$

Introduction

(ex. :α-quartz)

the strong SOI with the broken space inversion symmetry

allows appearance of Weyl nodes

Band gap : Te 0.323, Se 2.0 (eV)

V. B. Anzin *et al.*, Phys. Stat. Sol. (a) **42**, 385 (1977).

S. Tutihasi et al., Phys. Rev. 158, 623 (1967).



Structure of Te and Se

 <u>helical chains</u> either right-handed or left-handed

Electronic band structures of Te and Se



V. B. Anzin *et al.*, Phys. Stat. Sol. (a) **42**, 385 (1977).
S. Tutihasi *et al.*, Phys. Rev. **158**, 623 (1967).

Electronic band structure under pressure Hirayama, et al., PRL 114, 206401 (2015)

Low \rightarrow Increase pressure \rightarrow High



Te becomes the Weyl semimetal under pressure.

It is a first proposal of Weyl semimetals for real materials with broken inversion symmetry.

Motion of Weyl Nodes: topological nature



Fermi Surface and Spin Texture of Te



c.f. Rashba system



The Fermi surface around the H point has a hedgehog spin structure.

Hirayama, et al., PRL 114, 206401 (2015) Chiral transport in crystals with helical structure current-induced orbital magnetization

Electric current flowing through a helical crystal generates a magnetization.



Current-induced orbital magnetization

<u>Model</u>

An infinite stack of honeycomb lattice layers with a helical structure



$$H = t_1 \sum_{\langle ij \rangle} c_i^{\dagger} c_j + t_2 \sum_i \xi_i c_i^{\dagger} c_j$$

 t_1 : nearest neighbor hopping

 t_2 :helical hopping between the same sublattice in the neighboring layers



Formalism for current induced orbital magnetization

Orbital magnetization (Ceresoli et al, Xiao et al. (2006))

$$\boldsymbol{M}_{\text{orb}} = \frac{e}{2\hbar} \operatorname{Im} \sum_{n} \int_{BZ} \frac{d^3 \boldsymbol{k}}{(2\pi)^3} f_{n\boldsymbol{k}} \langle \partial_{\boldsymbol{k}} u_{n\boldsymbol{k}} | \times (H_{\boldsymbol{k}} + \varepsilon_{n\boldsymbol{k}} - 2\varepsilon_F) | \partial_{\boldsymbol{k}} u_{n\boldsymbol{k}} \rangle$$

df

Apply electric field (// helical axis)

Boltzmann approximation



distribution function :
$$f_{nk} = f_{nk}^0 + eE_z \tau v_{n,z} \frac{df}{d\varepsilon}\Big|_{\varepsilon = \varepsilon_{nk}}$$

For a metal, the orbital magnetization is induced by an electric current.

parameters : $t_2 = t_1/3$





• The directions of the magnetization is opposite for the right-handed and left-handed helix. Quantum mechanical analog of solenoid!

• The orbital magnetization is enhanced around the Dirac points.



Current-induced spin magnetization



spin-orbit interaction

 λ :spin-dependent nearest neighbor hopping

 λ_{xy} , λ_z :spin-dependent helical hopping between the sublattice in the neighboring layers

Spin texture

Band structure: $t_1 = 1, \lambda = -0.06, \lambda_{xy} = 0.05, \lambda_z = 0.05$





A radial spin texture around the H point (similar to Te)

Different from Rashba systems



Current-induced spin magnetization

We apply an electric field along the helical axis.

$$M_{\text{spin},z} = -\frac{eE\tau\mu_B}{\hbar} \sum_n \int_{\text{BZ}} \frac{d^3k}{(2\pi)^3} \frac{df}{d\epsilon} \Big|_{\epsilon=\epsilon_{nk}} \left\langle u_{nk} \left| \frac{\partial H_k}{\partial k_z} \right| u_{nk} \right\rangle \langle u_{nk} | s_z | u_{nk} \rangle$$

z-component of spin magnetization
$$t_1 = 1, \lambda_{xy} = 0.05, \lambda_z = 0.05, \Delta = 0.4$$

$$\int_{\substack{0.06 \\ 0.04 \\ 0.02 \\ 0.02 \\ 0.04 \\ -0.06 \\ -0.02 \\ -0.04 \\ -0.06 \\ -0.06 \\ -0.02 \\ -0.04 \\ -0.06 \\$$

Chiral transport in CNTs



Chiral nanotube breaks inversion & mirror symmetries \rightarrow chiral transport is allowed



Calculation of Chiral transport

<conductivity>:

Boltzmann transport,

constant relaxation time





Chiral conductivity for nanotubes with various chiralities



For fixed (small) carrier concentration..

- n-m=3N : σ₁₂=0
- n-m=3N+2: σ₁₂>0
- n-m=3N+1: σ₁₂<0

It can be understood from the warped Fermi surface





Chiral conductivity for (8,6) nanotube



Kinks as a function of carrier concentration

 \rightarrow Due to subband structures

Decompose into subband contributions:



Conclusions



- Weyl semimetals (in inversion asymmetric systems)
 - In topological insulator (TI) normal insulator (NI) phase transition, Weyl semimetals naturally appear
 - Combine with space group symmetry
 → powerful way for searching topological phases
 e.g. Tellurium: Weyl semimetal at high pressure
- Chiral transport in crystals with helical lattice structure
 - analogy with solenoid
 - Current induced orbital & spin magnetization
 - Example:
 - 3D chiral crystals: Tellurium etc.
 - chiral CNT

